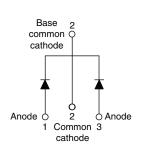


Vishay Semiconductors

Schottky Rectifier, 2 x 30 A

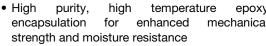


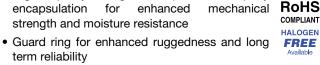


PRODUCT SUMMARY						
Package	TO-220AB					
I _{F(AV)}	2 x 30 A					
V_{R}	30 V					
V _F at I _F	0.44 V					
I _{RM} max.	350 mA at 125 °C					
T _J max.	150 °C					
Diode variation	Common cathode					
E _{AS}	13 mJ					

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation





- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS VALUES UNITS								
I _{F(AV)}	Rectangular waveform (per device)	60	Α						
V _{RRM}		30	V						
I _{FRM}	T _C = 120 °C (per leg)	60	۸						
I _{FSM}	t _p = 5 μs sine	1500	A						
V _F	30 A _{pk} , T _J = 125 °C	0.44	V						
T _J	Range	- 65 to 150	°C						

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-62CTQ030PbF	VS-62CTQ030-N3	UNITS			
Maximum DC reverse voltage	V _R	30	30	V			
Maximum working peak reverse voltage	V _{RWM}	30	30	V			

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average	oer leg		50.0/ d. t		30		
forward current per device		I _{F(AV)}	50 % duty cycle at T _C = 120 °C, rectangular waveform		60		
Peak repetitive forward current per leg	9	I _{FRM}	Rated V _R , square wave, 20 kHz, T _C = 127 °C		60	Α	
Maximum peak one cycle non-repetitive surge current per leg		I	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	1500		
		I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	300		
Non-repetitive avalanche energy per l	eg	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 3 \text{A}, L = 2.9 \text{mH}$		13	mJ	
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3	Α	



VS-62CTQ030PbF, VS-62CTQ030-N3

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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS			MAX.	UNITS	
Maximum forward voltage drop		30 A	T _{.1} = 25 °C	0.46	0.5	V	
	V _{FM} ⁽¹⁾	60 A	1J=25 C	0.56	0.6		
		30 A	T 105 %O	0.39	0.44		
		60 A	T _J = 125 °C	0.54	0.59		
Maximum instantaneous reverse current	I _{RM}	T _J = 25 °C	Rated DC voltage	0.4	2.5	mA	
Maximum instantaneous reverse current		T _J = 125 °C	hated DC voltage	180	350	IIIA	
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz) 25 °C		30	000	pF	
Typical series inductance	L _S	Measured from top of terminal to mounting plane			.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R	10	000	V/µs		

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		BOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction temperature ra	nge T _J			- 65 to 150	°C		
Maximum storage temperature rar	nge T _{Ste}	g		- 65 to 175	30		
Maximum thermal resistance, junction to case per leg		IC	DC operation	1.2	°C/W		
Typical thermal resistance, case to heatsink	R _{thC}	R _{thCS} Mounting surface, smooth and greased		0.50	C/VV		
Approximate weight				2	g		
Approximate weight				0.07	OZ.		
	inimum		Non-lubricated threads	6 (5)	kgf · cm		
Mounting torque ma	aximum		Non-lubricated tirreads	12 (10)	$(lbf \cdot in)$		
Marking device Case style TO-220AB		62CT	Q030				

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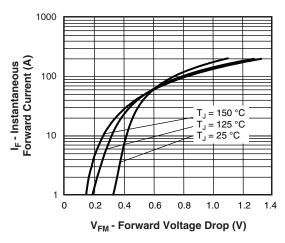


Fig. 1 - Maximum Forward Voltage Drop Characteristics

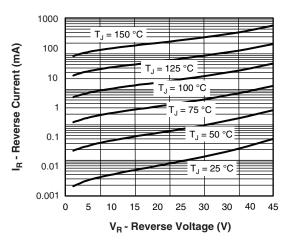


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

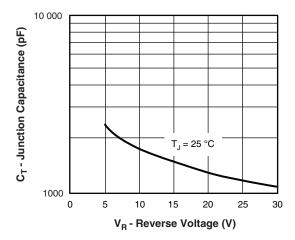


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

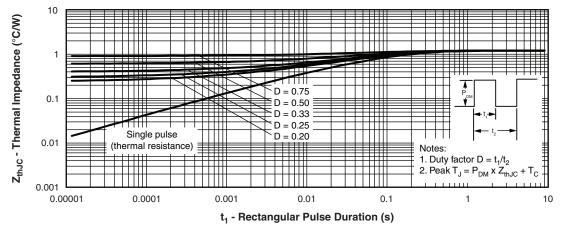


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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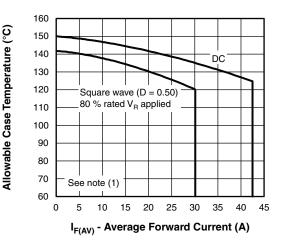


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

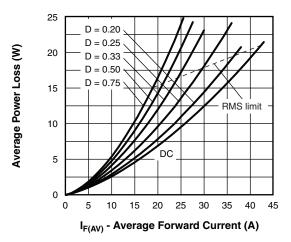


Fig. 6 - Forward Power Loss Characteristics

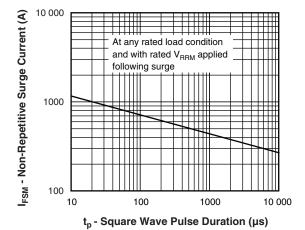


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

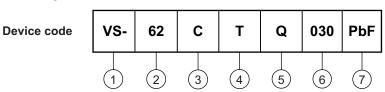
Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (\text{Pd} + \text{Pd}_{\text{REV}}) \times \text{R}_{\text{thJC}}; \\ \text{Pd} = \text{Forward power loss} = I_{\text{F(AV)}} \times \text{V}_{\text{FM}} \text{ at } (I_{\text{F(AV)}}/D) \text{ (see fig. 6)}; \\ \text{Pd}_{\text{REV}} = \text{Inverse power loss} = \text{V}_{\text{R1}} \times \text{I}_{\text{R}} \text{ (1 - D)}; I_{\text{R}} \text{ at } \text{V}_{\text{R1}} = 80 \text{ \% rated V}_{\text{R}} \\ \end{array}$

VS-62CTQ030PbF, VS-62CTQ030-N3

Vishay Semiconductors

ORDERING INFORMATION TABLE



1 - Vishay Semiconductors product

2 - Current rating (60 = 60 A)

3 - Circuit configuration

C = Common cathode

4 - Package

T = TO-220

5 - Schottky "Q" series

Voltage rating (030 = 30 V)

7 - Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-62CTQ030PbF	50	1000	Antistatic plastic tube				
VS-62CTQ030-N3	50	1000	Antistatic plastic tube				

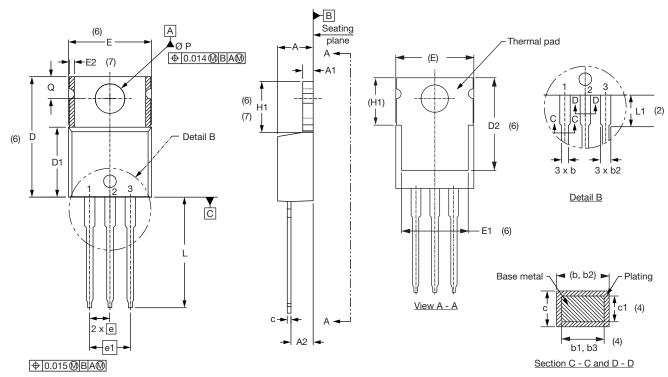
LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?95222</u>						
Death are adding a information	TO-220AB PbF	www.vishay.com/doc?95225				
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028				
SPICE model		www.vishay.com/doc?95185				



Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches



Lead assignments

Diodes

- 1. Anode/open
- 2. Cathode
- 3. Anode

Conforms to JEDEC outline TO-220AB

SYMBOL	MILLIN	MILLIMETERS		INCHES		
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.25	4.65	0.167	0.183		
A1	1.14	1.40	0.045	0.055		
A2	2.56	2.92	0.101	0.115		
b	0.69	1.01	0.027	0.040		
b1	0.38	0.97	0.015	0.038	4	
b2	1.20	1.73	0.047	0.068		
b3	1.14	1.73	0.045	0.068	4	
С	0.36	0.61	0.014	0.024		
c1	0.36	0.56	0.014	0.022	4	
D	14.85	15.25	0.585	0.600	3	
D1	8.38	9.02	0.330	0.355		
D2	11.68	12.88	0.460	0.507	6	

SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° t	o 93°	90° t	o 93°	
		•	•	•	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

Lead tip



Legal Disclaimer Notice

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